

ALL RIGHTS RESERVED. NO PORTION OF THIS PUBLICATION, WHETHER IN WHOLE OR IN PART CAN BE REPRODUCED WITHOUT THE EXPRESS WRITTEN CONSENT OF SPC TECHNOLOGY.

			REVISIONS	DOC. NO. SPC-F005 * Effective: 7/8/02 * DCP No: 1398								
DCP	#	REV	DESCRIPTION	DRAWN	DATE	CHECKD	DATE	APPRVD	DATE			
126	2	Α	RELEASED	но	2/4/03	JWM	2/4/03	S	2/4/03			
188	5	В	UPDATED TO ROHS COMPLIANT	ΕO	02/03/06	НО	2/6/06	НО	2/6/06			

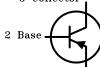
RoHS
Compliant

## Absolute Maximum Ratings:

- Collector-Emitter Voltage,  $V_{CEO} = 50V$
- Collector-Base Voltage,  $V_{CBO}=75V$  Emitter-Base Voltage,  $V_{EBO}=5V$  Continuous Collector Current,  $I_{C}=2A$
- Base Current,  $I_R = 1A$
- Total Power Dissipation ( $T_C = +25^{\circ}C$ ),  $P_D = 10W$ 
  - Derate Above  $25^{\circ}C = 0.057 \text{nW/}^{\circ}C$
- Operating Junction Temperature Range,  $T_J=-65^\circ$  to  $+200^\circ$ C Storage Temperature Range,  $T_{stg}=-65^\circ$  to  $+200^\circ$ C Thermal Resistance, Junction—to—Case,  $R_{thJC}=17.5^\circ$ C/W

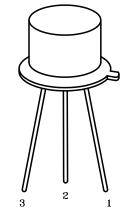
## PNP



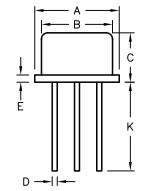


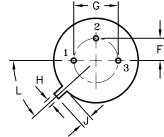


Min Man Hait



- 1. EMITTER
- 2. BASE
- 3 Collector





					, Ju							
Dimensions	A	В	С	D	E	F	G	Н	J	K	L	
Min.	8.50	7.74	6.09	0.40	_	2.41	4.82	0.71	0.73	12.70	45°	
Max.	9.39	8.50	6.60	0.53	0.88	2.66	5.33	0.86	1.02	_	48°	
					•	•						

## Electrical Characteristics: $(T_A = +25^{\circ}C \text{ Unless otherwise specified})$ Symbol Test Conditions

SPC-F005.DWG

Parameter	Symbol	Min	Max	Unit	
OFF Characteristics					
Collector—Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	$I_{\rm C}$ = 100mA, $I_{\rm B}$ = 0 (Note 1)	50	1	٧
Collector Cutoff Current	I <sub>CEX</sub>	$V_{CE} = 75V, V_{BE} = 1.5V$	_	0.1	mΑ
		$V_{CE} = 45V, V_{BE} = 1.5V, T_{C} = +150^{\circ}C$	_	5.0	mΑ
Emitter Cutoff Current	I <sub>EBO</sub>	$V_{BE} = 5V, I_{C} = 0$	_	0.1	mΑ
ON Characteristics (Note 1)					
DC Current Gain	h <sub>FE</sub>	$I_C = 500$ mA, $V_{CE} = 4V$	40	250	-
Collector—Emitter Saturation Voltage	V <sub>CE(sat)</sub>	$I_{C} = 500$ mA, $I_{B} = 50$ mA	_	1.2	٧
Base—Emitter ON Voltage	V <sub>BE(on)</sub>	$I_C$ = 500mA, $V_{CE}$ = 4V	_	1.4	٧
Small-Signal Characteristics			•		
Small—Signal Current Gain	hfe	$I_{C}$ = 50mA, $V_{CE}$ = 4V, f = 10MHz	5.0	_	i –
Switching Characteristics			•		
Turn-On Time	ton	$V_{CC}=30V,\ I_{C}=500$ mA, $I_{B1}=50$ mA	_	100	ns
Turn-Off Time	t <sub>off</sub>	$V_{CC} = 30V, I_{C} = 500mA, I_{B1} = I_{B2} = 50mA$	_	1000	l ns

ALL STATEMENTS AND TECHNICAL INFORMATION CONTAINED HEREIN ARE BASED UPON INFORMATION AND/OR TESTS WE BELIEVE TO BE ACCURATE AND RELIABLE. SINCE CONDITIONS OF USE ARE BEYOND OUR CONTROL, THE USER SHALL DETERMINE THE SUITABILITY OF THE PRODUCT FOR THE INTENDED USE AND ASSUME ALL RISK AND LIABILITY WHATSOEVER IN CONNECTION THEREWITH.

**TOLERANCES:** 

UNLESS OTHERWISE SPECIFIED, DIMENSIONS ARE FOR REFERENCE PURPOSES ONLY.

DRAWN BY:	DATE:
HISHAM ODISH	2/4/03
CHECKED BY:	DATE:
JEFF MCVICKER	2/4/03
APPROVED BY:	DATE:
JOHN COLF	2/4/03

DRAWING TITLE:

Silicon TO-39 PNP Conoral Purpose

	11	ransisior,	Silic	on,	10-39,	LINE	, 6	enerai	rurpos	se			
	SIZE	DWG. NO.					ELEC	CTRONIC FI	LE	REV			
3	Α	2N5323						35C0723.DWG					
	SCALE	- NTS		шс	) M · Millimete	rs		SHEET	1 0	F 1			